

# The RF Line

## NPN Silicon

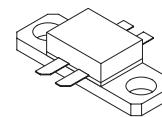
### RF Power Transistor

Designed for 24 Volt UHF large-signal, common emitter, class-AB linear amplifier applications in industrial and commercial FM/AM equipment operating in the range 800–970 MHz.

- Specified 24 Volt, 900 MHz Characteristics
  - Output Power = 30 Watts
  - Minimum Gain = 10.5 dB @ 900 MHz, class-AB
  - Minimum Efficiency = 30% @ 900 MHz, 30 Watts (PEP)
  - Maximum Intermodulation Distortion –30 dBc @ 30 Watts (PEP)
- Characterized with Series Equivalent Large-Signal Parameters from 800 to 960 MHz
- Silicon Nitride Passivated
- 100% Tested for Load Mismatch Stress at all Phase Angles with 5:1 VSWR @ 26 Vdc, and Rated Output Power
- Gold Metalized, Emitter Ballasted for Long Life and Resistance to Metal-Migration

**MRF897R**

30 W, 900 MHz  
RF POWER  
TRANSISTOR  
NPN SILICON



CASE 395E-01, STYLE 1

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	30	Vdc
Collector-Emitter Voltage	$V_{CES}$	60	Vdc
Emitter-Base Voltage	$V_{EBO}$	4.0	Vdc
Collector-Current — Continuous	$I_C$	4.0	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	105 0.60	Watts W/ $^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	–65 to +150	$^\circ\text{C}$

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.67	$^\circ\text{C/W}$

#### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit

#### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ( $I_C = 50 \text{ mA}\text{dc}$ , $I_B = 0$ )	$V_{(BR)CEO}$	30	33	—	Vdc
Collector-Emitter Breakdown Voltage ( $I_C = 50 \text{ mA}\text{dc}$ , $V_{BE} = 0$ )	$V_{(BR)CES}$	60	80	—	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 5 \text{ mA}\text{dc}$ , $I_C = 0$ )	$V_{(BR)EBO}$	4.0	4.7	—	Vdc
Collector Cutoff Current ( $V_{CE} = 30 \text{ Vdc}$ , $V_{BE} = 0$ , $T_C = 25^\circ\text{C}$ )	$I_{CES}$	—	—	10.0	mA

#### ON CHARACTERISTICS

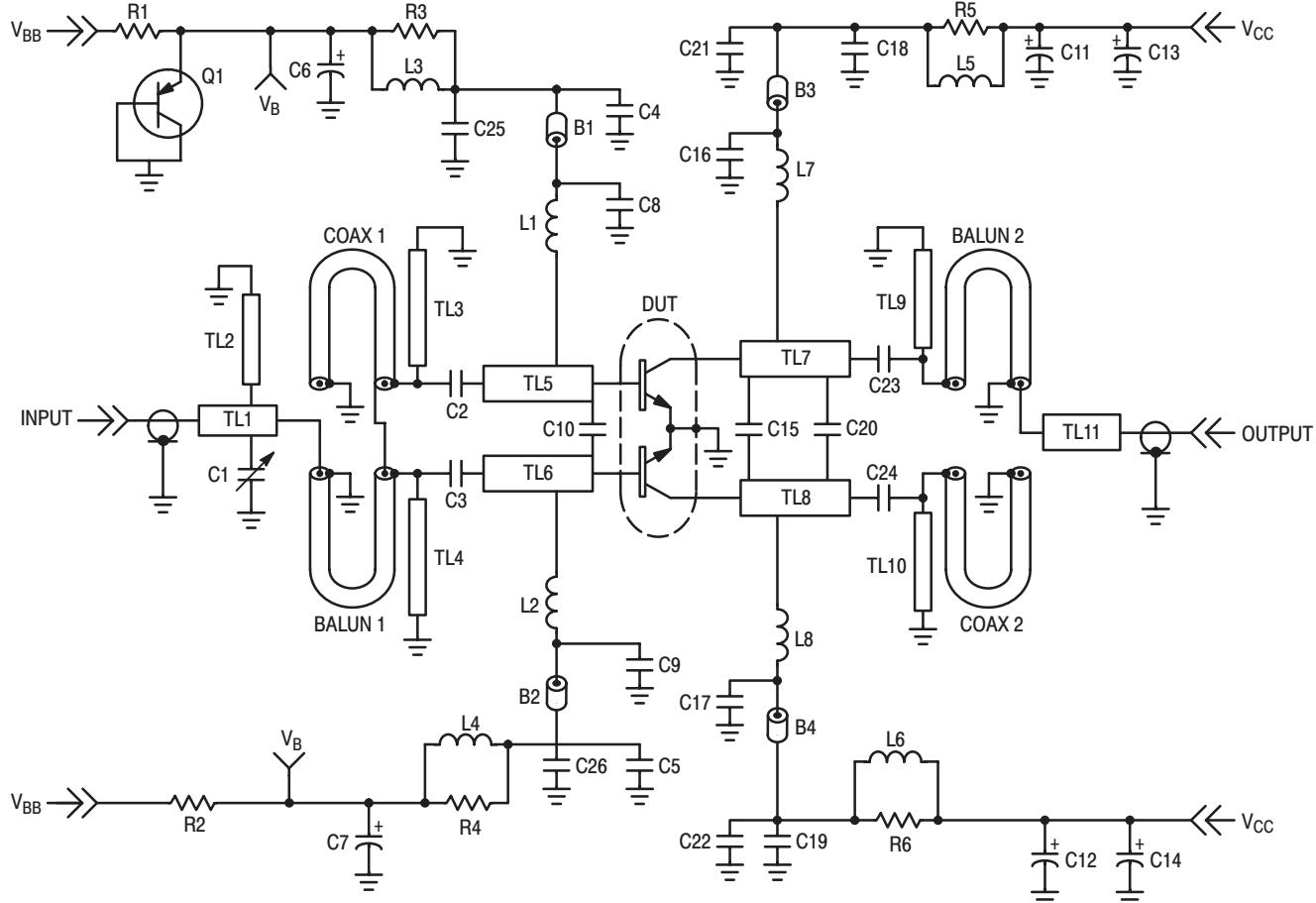
DC Current Gain ( $I_{CE} = 1.0 \text{ Adc}$ , $V_{CE} = 5 \text{ Vdc}$ )	$h_{FE}$	30	80	120	—

#### DYNAMIC CHARACTERISTICS

Output Capacitance ( $V_{CB} = 24 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{ob}$	14	21	28	pF
					(continued)

ELECTRICAL CHARACTERISTICS — continued ( $T_C = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>FUNCTIONAL CHARACTERISTICS</b>					
Common-Emitter Amplifier Power Gain ( $V_{CC} = 24$ Vdc, $P_{out} = 30$ Watts (PEP), $I_{cq} = 125$ mA, $f_1 = 900$ MHz, $f_2 = 900.1$ MHz)	$G_{pe}$	10.5	12.0	—	dB
Collector Efficiency ( $V_{CC} = 24$ Vdc, $P_{out} = 30$ Watts (PEP), $I_{cq} = 125$ mA, $f_1 = 900$ MHz, $f_2 = 900.1$ MHz)	$\eta$	30	38	—	%
Intermodulation Distortion ( $V_{CC} = 24$ Vdc, $P_{out} = 30$ Watts (PEP), $I_{cq} = 125$ mA, $f_1 = 900$ MHz, $f_2 = 900.1$ MHz)	IMD	—	-37	-30	dBc
Output Mismatch Stress ( $V_{CC} = 26$ Vdc, $P_{out} = 30$ Watts (PEP), $I_{cq} = 125$ mA, $f_1 = 900$ MHz, $f_2 = 900.1$ MHz, Load VSWR = 5:1 (all phase angles))	$\psi$	No Degradation in Output Power			



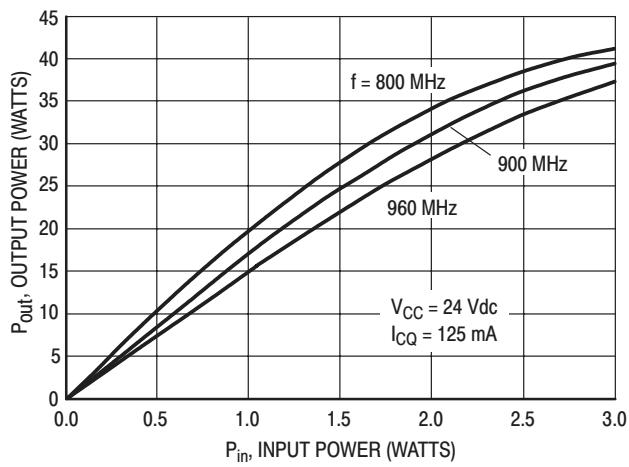


Figure 2. Output Power versus Input Power

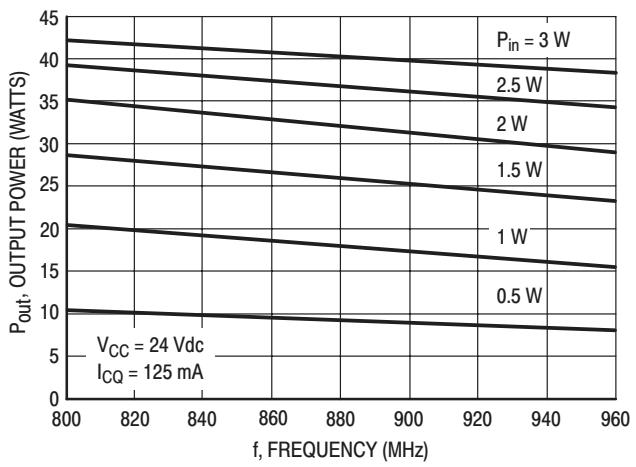


Figure 3. Output Power versus Frequency

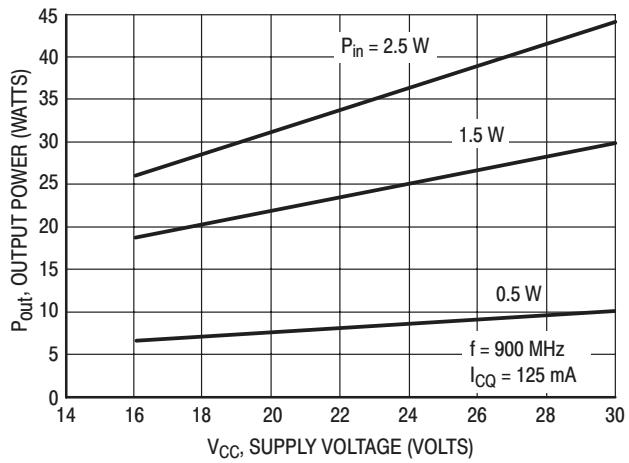


Figure 4. Output Power versus Supply Voltage

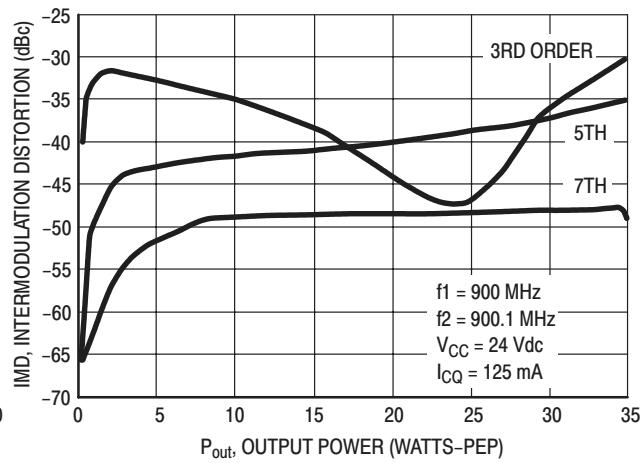


Figure 5. Intermodulation versus Output Power

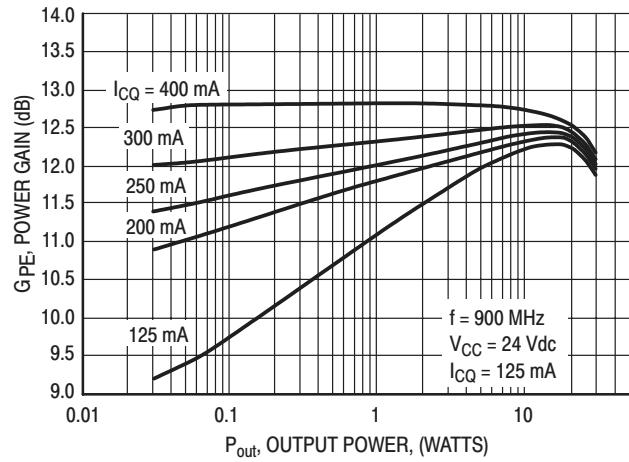


Figure 6. Power Gain versus Output Power

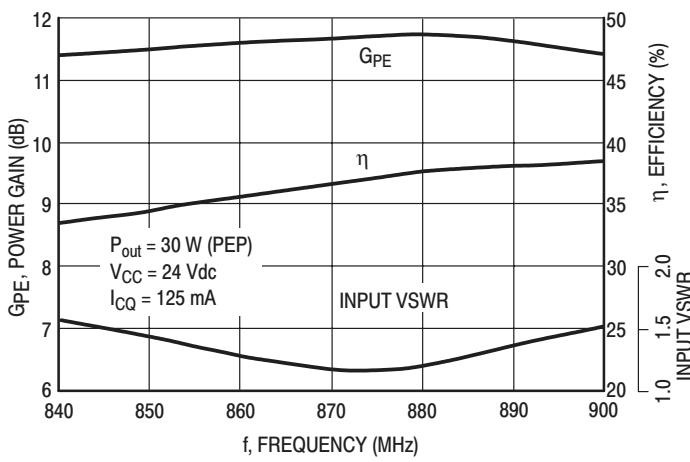
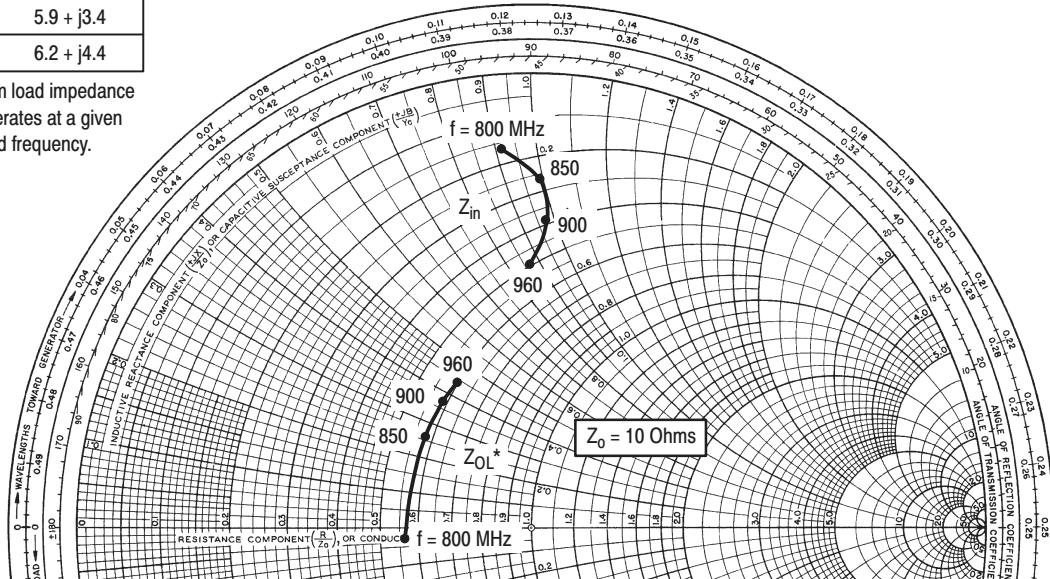


Figure 7. Broadband Test Fixture Performance

$P_{out} = 30$  W (PEP),  $V_{CC} = 24$  V

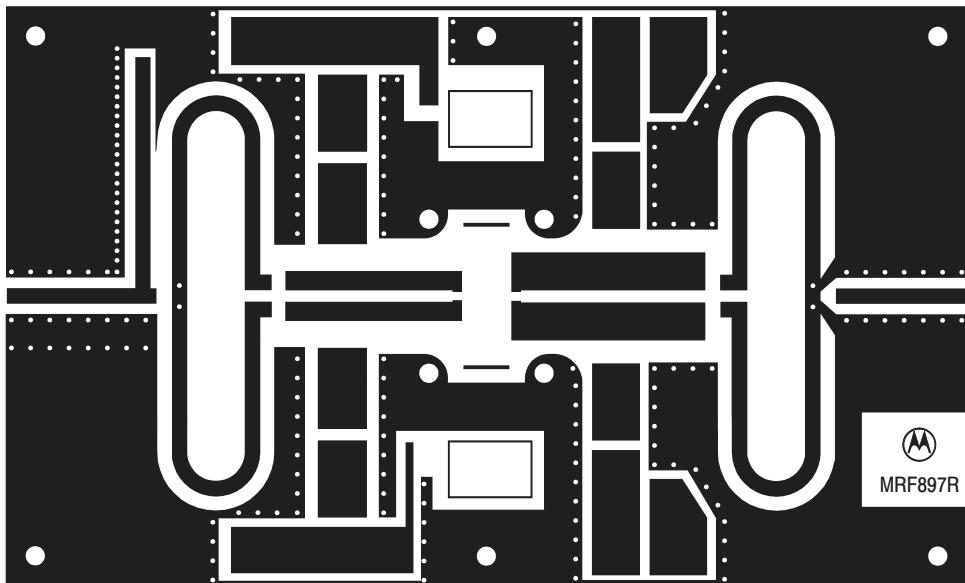
$f$ MHz	$Z_{in}$ Ohms	$Z_{OL^*}$ Ohms
800	$1.7 + j9.2$	$5.9 - j0.4$
850	$2.6 + j10$	$5.7 + j2.6$
900	$4 + j9.9$	$5.9 + j3.4$
950	$5 + j8.8$	$6.2 + j4.4$

$Z_{OL^*}$  = Conjugate of the optimum load impedance into which the device operates at a given output power, voltage and frequency.



NOTE:  $Z_{in}$  &  $Z_{OL^*}$  are given from base-to-base and collector-to-collector respectively.

Figure 8. Series Equivalent Input/Output Impedances



(SCALE: 1:1)

Figure 9. MRF897R Photomaster  
(Reduced 18% in printed data book, DL110/D)

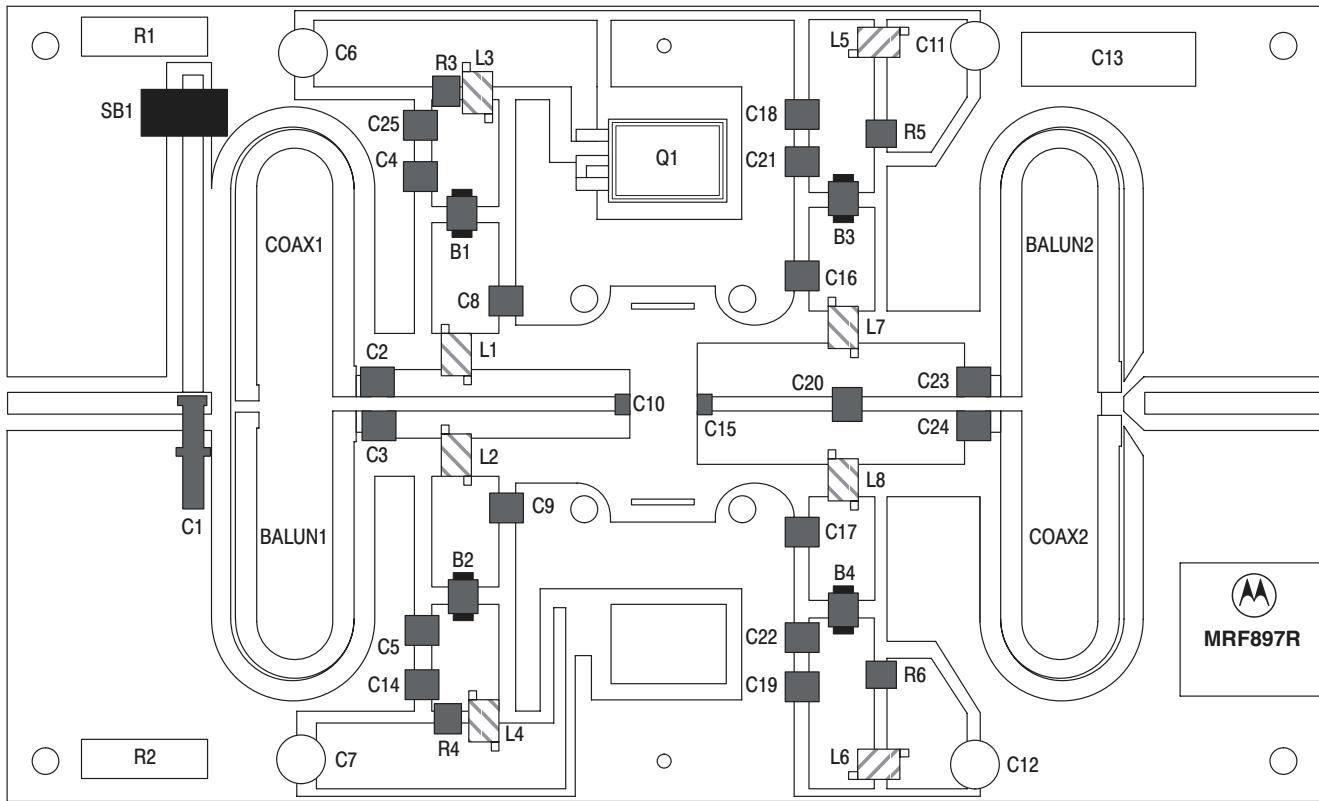
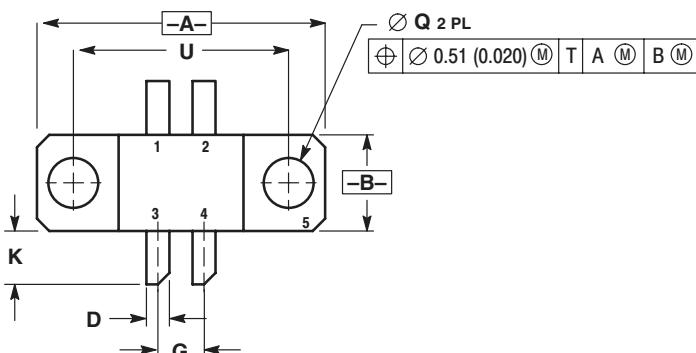


Figure 10. 840–900 MHz Test Circuit Component Layout

# NOTES

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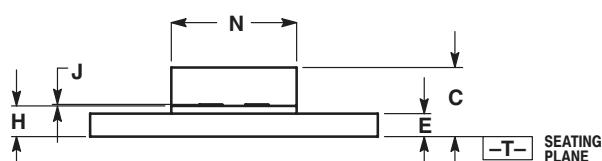
## PACKAGE DIMENSIONS



NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.739	0.750	18.77	19.05
B	0.240	0.260	6.10	6.60
C	0.165	0.198	4.19	5.03
D	0.055	0.065	1.40	1.65
E	0.055	0.070	1.40	1.78
G	0.110	0.130	2.79	3.30
H	0.079	0.091	2.01	2.31
J	0.003	0.005	0.08	0.13
K	0.120	0.150	3.05	3.81
N	0.315	0.330	8.00	8.38
Q	0.125	0.135	3.18	3.42
U	0.560 BSC		14.23 BSC	

STYLE 1:  
 PIN 1. BASE  
 2. BASE  
 3. COLLECTOR  
 4. COLLECTOR  
 5. Emitter



CASE 395E-01  
ISSUE O

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